

## 产品规格书

### Specification of Products

产品名称：快恢复二极管

产品型号：MURP100100CI

浙江世菱半导体有限公司  
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### Ultra-Fast Soft Recovery Diode Module

#### Description

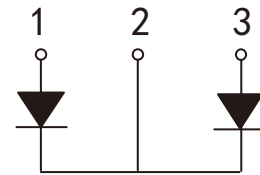
Ultra-FRD module devices are optimized to reduce losses and EMI/RFI in high frequency power conditioning electrical systems. These diode modules are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

#### Equivalent Circuit and Package

#### Features

- ☞ Repetitive Reverse Voltage :  $V_{RRM}=100V$
- ☞ Low Forward Voltage Drop :  $V_F$  (typ.) = 1.0V
- ☞ Average Forward Current :  $I_F(AV.) = 400A$  @  $T_c=125^\circ C$
- ☞ Ultra-Fast Reverse Recovery Time :  $t_{rr}$ (typ.) = 65 ns
- ☞ Extensive Characterization of Recovery Parameters
- ☞ Reduced EMI and RFI
- ☞ Non Isolation Type Package

#### Equivalent Circuit



#### Applications

Motor Drives, Free wheel use, High Power Converters, Welders, Various Switching and Telecommunication Power Supply

#### Absolute Maximum Ratings @ $T_j=25^\circ C$ (Per Leg)

Symbol	Parameter	Conditions	Ratings	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		100	V
$V_{R(DC)}$	Reverse DC Voltage		50	V
$I_{F(AV)}$	Average Forward Current @ $T_c=25^\circ C$ @ $T_c = 100^\circ C$	Resistive Load	200 100	A A
$I_{FSM}$	Surge (non-repetitive) Forward Current	One Half Cycle at 60Hz, Peak Value	1000	A
$I^2_t$	$I^2t$ for Fusing	Value for One Cycle Current, $t_w= 8.3ms, T_j= 25^\circ C$ Start	$98 \times 10^{-3}$	$A^2 s$
$T_j$	Junction Temperature		-40 ~ 125	$^\circ C$
$T_{stg}$	Storage Temperature		-40 ~ 125	$^\circ C$
$P_d$	Maximum Power Dissipation		1010	W
-	Mounting Torque		5.0	N.m
-	Terminal Torque		5.0	N.m

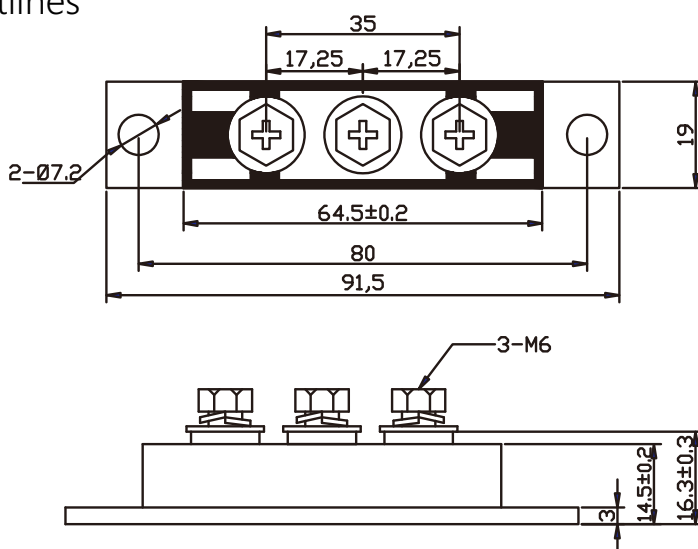
### Thermal Characteristics

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal Resistance	Junction to Case	-	-	0.10	°C/W

### Electrical Characteristics @ $T_j=25^{\circ}\text{C}$ (unless otherwise specified)

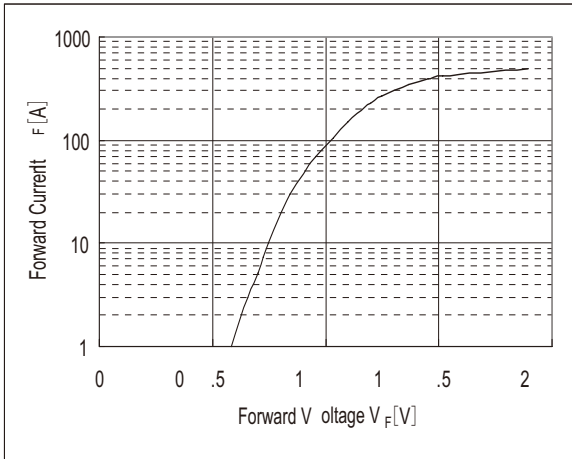
Symbol	Parameter	Conditions	Values			Unit	
			Min.	Typ.	Max.		
$V_R$	Cathode Anode Breakdown Voltage	$I_R = 100\mu\text{A}$	100	-	-	V	
$V_{FM}$	Maximum Forward Voltage	$I_{FM} = 300\text{A}, T_c = 25^{\circ}\text{C}$	-	1.0	1.1	V	
		$I_{FM} = 300\text{A}, T_c = 100^{\circ}\text{C}$	-	0.7	0.8	V	
$I_{RRM}$	Repetitive Peak Reverse Current	$T_c = 100^{\circ}\text{C}, V_{RRM}$ applied	-	-	10.0	mA	
$t_{rr}$	Reverse Recovery Time	$I_{FM} = 100\text{A}, V_R = 150\text{V}, di/dt = -100\text{A}/\mu\text{s}$	$T_c = 25^{\circ}\text{C}$	-	65	70	ns
			$T_c = 100^{\circ}\text{C}$	-	100	-	ns

### Package Outlines

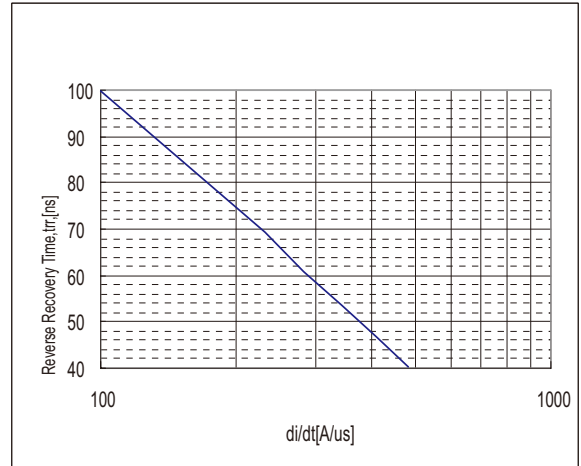


Unit:mm

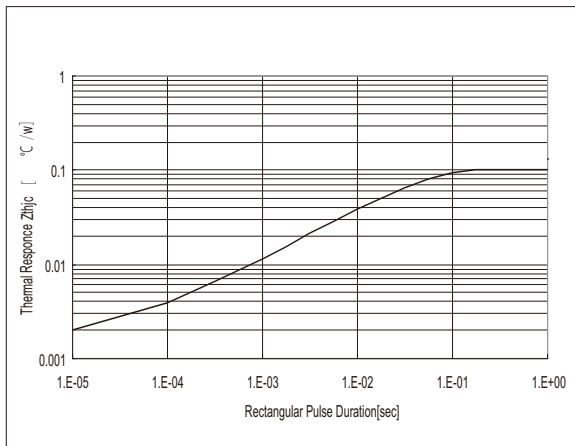
## Performance Curves



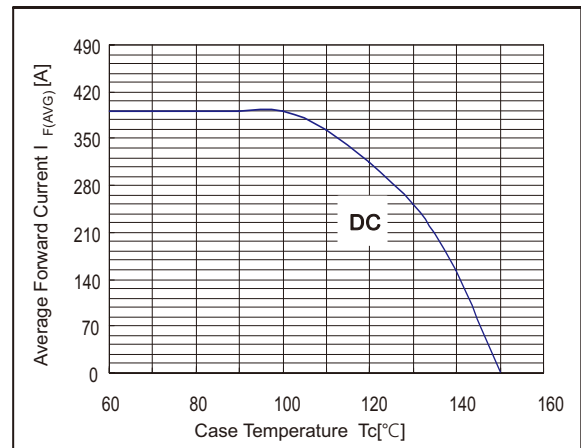
**Fig. 1 : Typical Forward Voltage Drop vs. Instantaneous Forward Current**



**Fig. 2 : Typical Reverse Recovery Time vs.  $-di/dt$**



**Fig. 3 : Transient Thermal Impedance ( $Z_{thjc}$ ) Characteristics**



**Fig. 4 : Forward Current Derating Curve**